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20 V, 4.1 A P-channel Trench MOSFET Rev. 1 — 21 April 2011

Product data sheet

#### **Product profile** 1.

### **1.1 General description**

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### **1.2 Features and benefits**

- Low R<sub>DSon</sub>
- Very fast switching

### **1.3 Applications**

- Relay driver
- High-speed line driver

- Trench MOSFET technology
- High-side loadswitch
- Switching circuits

### 1.4 Quick reference data

Table 1.	Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-20	V
$V_{GS}$	gate-source voltage			-12	-	12	V
I <sub>D</sub>	drain current	$V_{GS} = -4.5 \text{ V}; \text{ T}_{amb} = 25 \text{ °C}$	[1]	-	-	-4.1	А
Static cha	aracteristics						
$R_{DSon}$	drain-source on-state resistance	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -2.4 A; T <sub>j</sub> = 25 °C		-	48	55	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

#### **Pinning information** 2.

<b>Pin</b> 1	<b>Symbol</b> D	Description	Simplified outline	Graphic symbol
1	D			
		drain		5
2	D	drain		
3	G	gate	0	
4	S	source		
5	D	drain	SOT457 (TSOP6)	Ś
6	D	drain		017aaa094



# 3. Ordering information

g information		
Package		
Name	Description	Version
TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457
	Package Name	Package   Name Description

# 4. Marking

#### Table 4.Marking codes

Type number	Marking code
PMN48XP	ZV

# 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	$T_j = 25 \ ^{\circ}C$		-	-20	V
V <sub>GS</sub>	gate-source voltage			-12	12	V
I <sub>D</sub>	drain current	$V_{GS} = -4.5 \text{ V}; \text{ T}_{amb} = 25 \text{ °C}$	<u>[1]</u>	-	-4.1	А
		$V_{GS} = -4.5 \text{ V}; \text{ T}_{amb} = 100 \text{ °C}$	<u>[1]</u>	-	-2.5	А
I <sub>DM</sub>	peak drain current	$T_{amb} = 25 \text{ °C}$ ; single pulse; $t_p \le 10  \mu\text{s}$		-	-20	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	530	mW
			<u>[1]</u>	-	1285	mW
		T <sub>sp</sub> = 25 °C		-	6250	mW
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	in diode					
I <sub>S</sub>	source current	$T_{amb} = 25 \ ^{\circ}C$	[1]	-	-1.4	А

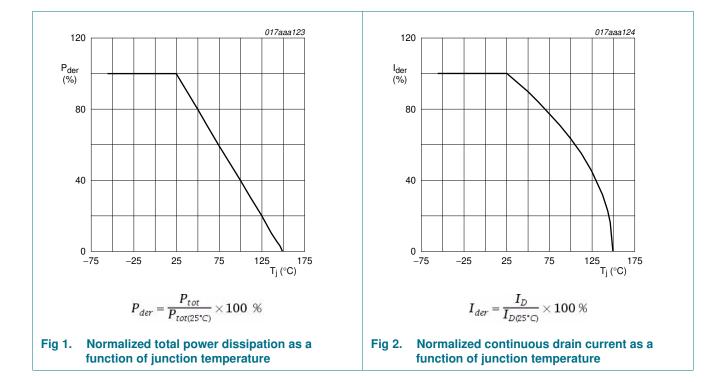
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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# PMN48XP

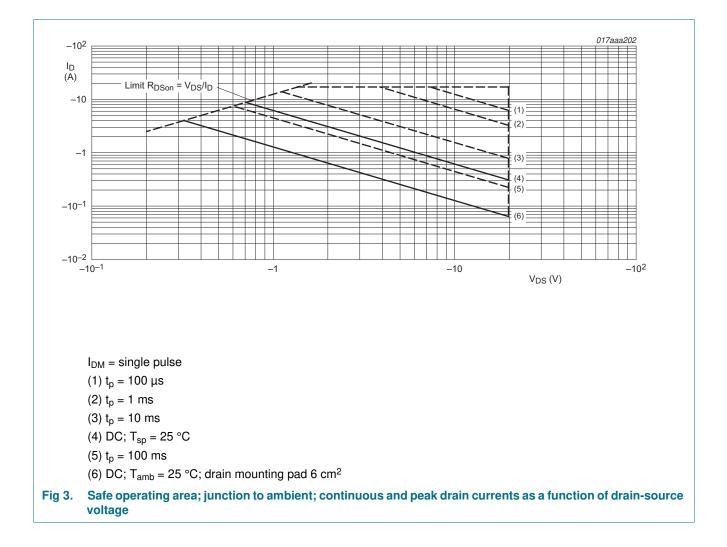
#### 20 V, 4.1 A P-channel Trench MOSFET



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#### 20 V, 4.1 A P-channel Trench MOSFET



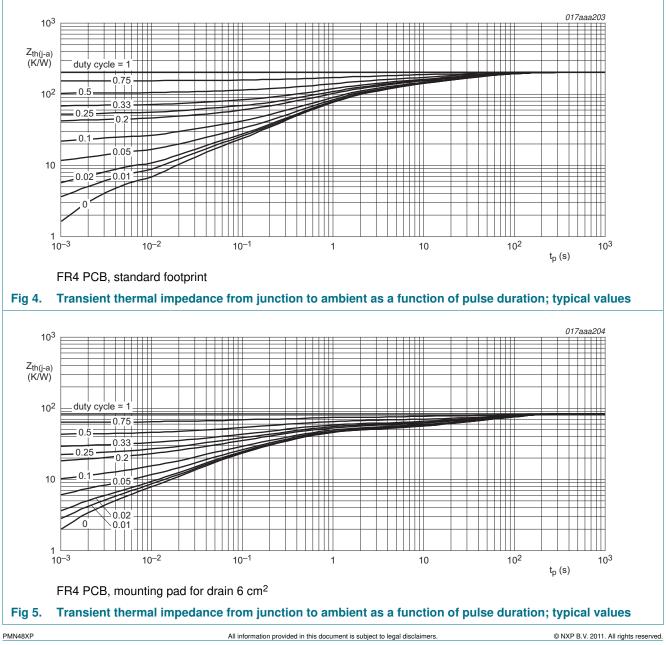
20 V, 4.1 A P-channel Trench MOSFET

# 6. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance	in free air	<u>[1]</u>	-	204	235	K/W
	from junction to ambient		[2]	-	84	97	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	17	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

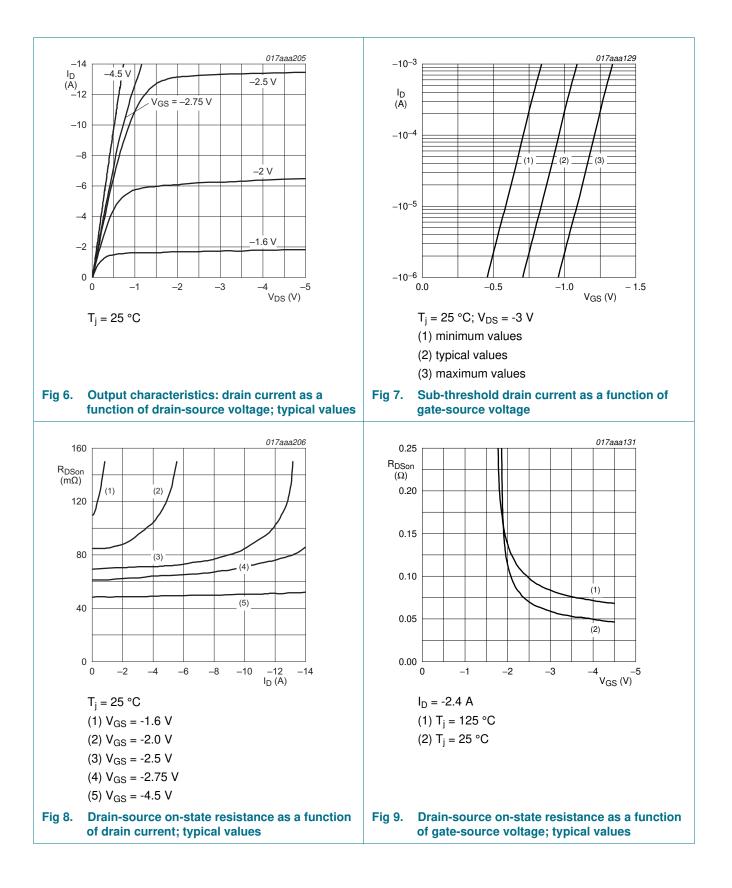


### 20 V, 4.1 A P-channel Trench MOSFET

# 7. Characteristics

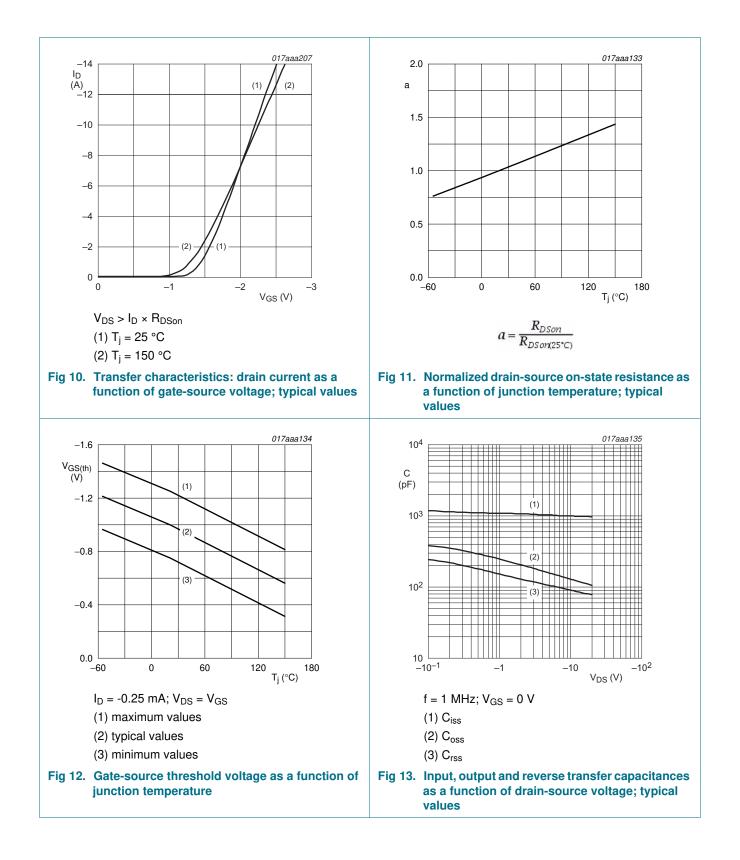
Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D = -250 \ \mu\text{A}; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^\circ\text{C}$	-20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D = -250 \ \mu\text{A}; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^\circ\text{C}$	-0.75	-1	-1.25	V
I <sub>DSS</sub>	drain leakage current	$V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-1	μA
		$V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$	-	-	-10	μA
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = -12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-100	nA
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -2.4 A; T <sub>j</sub> = 25 °C	-	48	55	mΩ
		$V_{GS}$ = -4.5 V; I <sub>D</sub> = -2.4 A; T <sub>j</sub> = 150 °C	-	70	80	mΩ
		$V_{GS}$ = -2.5 V; I <sub>D</sub> = -2 A; T <sub>j</sub> = 25 °C	-	72	82	mΩ
g <sub>fs</sub>	forward transconductance	$V_{DS} = -5 \text{ V}; \text{ I}_{D} = -2.4 \text{ A}; \text{ T}_{j} = 25 \text{ °C}$	-	10	-	S
Dynamic	characteristics					
Q <sub>G(tot)</sub>	total gate charge	$I_D = -1$ A; $V_{DS} = -10$ V; $V_{GS} = -4.5$ V;	-	8.7	13	nC
Q <sub>GS</sub>	gate-source charge	$T_j = 25 \ ^{\circ}C$	-	1.8	-	nC
$Q_{GD}$	gate-drain charge		-	1.7	-	nC
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 V; V_{DS} = -10 V; f = 1 MHz;$	-	1000	-	pF
C <sub>oss</sub>	output capacitance	$T_j = 25 \text{ °C}$	-	130	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	90	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -10 V; $V_{GS}$ = -5 V; $R_{G(ext)}$ = 6 $\Omega$ ;	-	15	-	ns
t <sub>r</sub>	rise time	$T_j = 25 \text{ °C}; I_D = -1 \text{ A}$	-	22	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	51	-	ns
t <sub>f</sub>	fall time		-	22	-	ns
Source-d	rain diode					
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -2.4 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.75	-1	V

#### 20 V, 4.1 A P-channel Trench MOSFET



Product data sheet

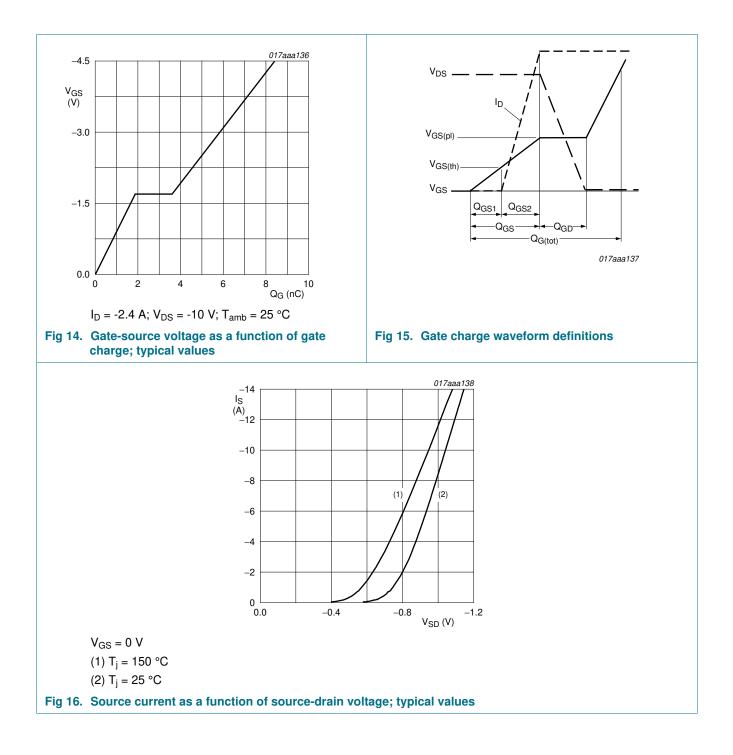
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#### 20 V, 4.1 A P-channel Trench MOSFET



20 V, 4.1 A P-channel Trench MOSFET

# 8. Package outline

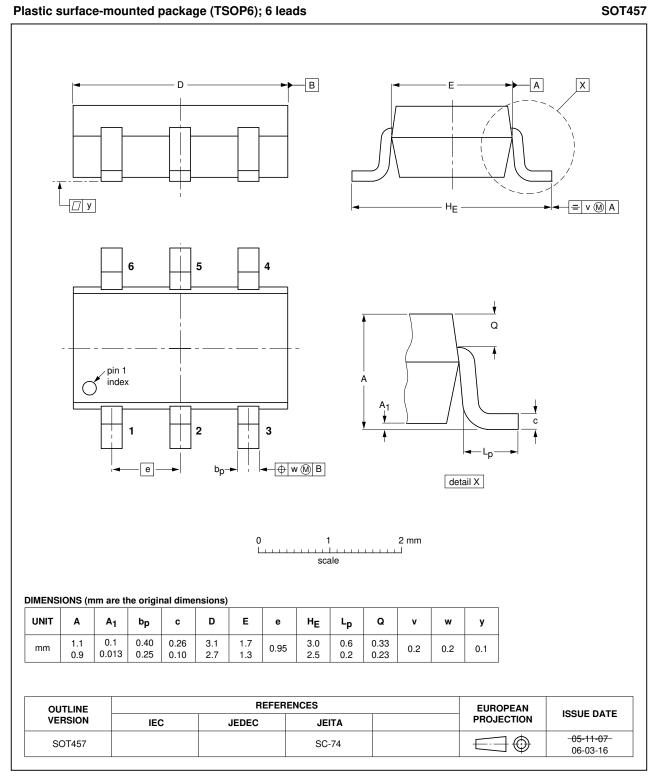
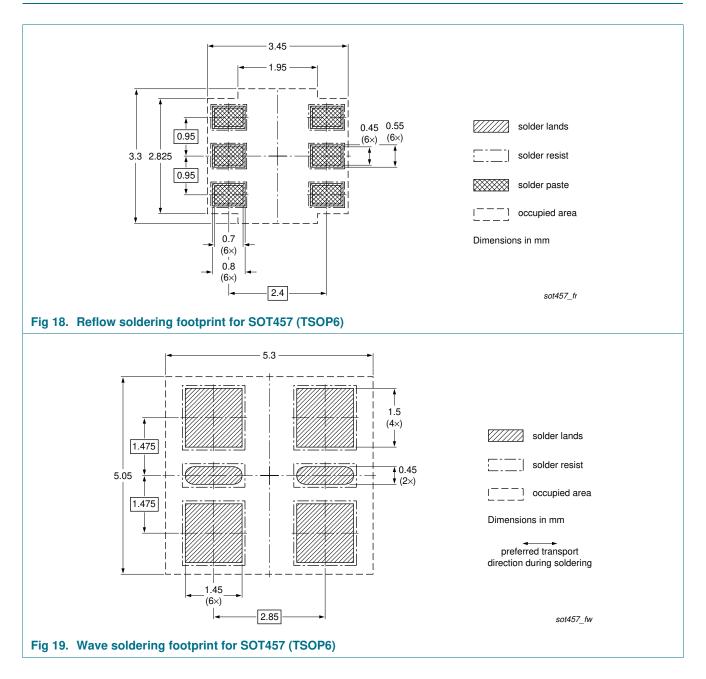


Fig 17. Package outline SOT457 (TSOP6)

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#### 20 V, 4.1 A P-channel Trench MOSFET

# 9. Soldering



### 20 V, 4.1 A P-channel Trench MOSFET

# 10. Revision history

Table 8.	Revision history						
Document	D	Release date	Data sheet status	Change notice	Supersedes		
PMN48XP v	v.1	20110421	Product data sheet	-	-		

# 11. Legal information

### 11.1 Data sheet status

Document status [1] [2]	Product status 3	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Product data sheet

#### 20 V, 4.1 A P-channel Trench MOSFET

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